Electronic correlations and unusual superconducting response in the optical properties of the iron chalcogenide FeTe_{0.55}Se_{0.45}

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The in-plane complex optical properties of the iron-chalcogenide superconductor $\text{FeTe}_{0.55}\text{Se}_{0.45}$ have been determined above and below the critical temperature $T_c=14$ K. At room temperature the conductivity is described by a weakly interacting Fermi liquid; however, below 100 K the scattering rate develops a frequency dependence in the terahertz region, signaling the increasingly correlated nature of this material. We estimate the dc conductivity $\sigma_{dc}(T \ge T_c) \simeq 3500 \pm 400 \ \Omega^{-1} \text{ cm}^{-1}$ and the superfluid density $\rho_{s0} \simeq 9 \pm 1 \times 10^6 \text{ cm}^{-2}$, which places this material close to the scaling line $\rho_{s0}/8 \simeq 8.1 \sigma_{dc} T_c$ for a BCS dirty-limit superconductor. Below T_c the optical conductivity reveals two gap features at $\Delta_{1,2} \simeq 2.5$ and 5.1 meV.

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The surprising discovery of superconductivity in the ironarsenic LaFeAsO_{1-x} F_x (1111) pnictide compound has prompted an intense investigation of this class of materials.^{1,2} The critical temperature T_c may be increased above 50 K through rare-earth substitutions.³ While the mechanism for superconductivity in many metals and alloys is mediated by lattice vibrations,⁴ the high values for T_c and the strong interplay between the magnetism and the lattice suggest that the superconductivity in this class of materials is not phonon mediated.⁵ In addition to searching for higher values of T_c in the 1111 family of materials, considerable effort has been made looking for superconductivity in other structurally simpler Fe-based systems. In metallic BaFe₂As₂ the application of pressure yields $T_c \simeq 29$ K while Co and Ni doping yields $T_c \approx 23$ K at ambient pressure.⁶⁻⁸ Superconductivity has also been observed in the As-free ironchalcogenide FeSe compound with $T_c=8$ K, which increases to $T_c = 27$ K with the application of pressure.^{9,10} By introducing Te, the critical temperature in $FeTe_{1-x}Se_x$ at ambient pressure reaches a maximum $T_c = 14$ K for x = 0.45. Despite these structural differences, the band structure of these materials is similar, with a minimal description consisting of an electron band (β) at the M point and a hole band (α) at the center of the Brillouin zone.¹¹ There have been a number of studies of the $Fe_{1+x}Te$ and $FeTe_{1-x}Se_x$ materials, including transport,^{12–15} tunneling¹⁶ and angle-resolved photoemission,^{17–20} with particular emphasis placed on the magnetic properties.^{20–25} While the optical properties of the superconducting iron-pnictide materials have been investigated in some detail,²⁶⁻³² in comparison the ironchalcogenide materials remain relatively unexplored.¹³

In this work we examine the in-plane complex optical properties of superconducting FeTe_{0.55}Se_{0.45} above and below T_c . Over much of the normal state the material is a weakly interacting Fermi liquid and the transport is Drude-like. However, close to T_c the Drude picture breaks down and the scattering rate adopts a strong frequency dependence, signaling the increasingly correlated nature of this material.^{19,33} The onset of superconductivity is clearly observed in the optical properties below T_c , and the optical conductivity suggests that in addition to a prominent gap feature at ≈ 5.1 meV, a second gap opens at ≈ 2.5 meV.

Single crystals with good cleavage planes (001) were grown by a unidirectional solidification method with a nominal composition of FeTe_{0.55}Se_{0.45} and a critical temperature determined by magnetic susceptibility of $T_c = 14$ K with a transition width of ≈ 1 K. The reflectance from the cleaved surface of a mm-sized single crystal has been measured at a near-normal angle of incidence for several temperatures above and below T_c over a wide frequency range (~2 meV to 4 eV) for light polarized in the *a-b* planes using an *in situ* overcoating technique.³⁴ The reflectance in the terahertz and far-infrared region (1 THz=33.4 cm⁻¹) is shown in Fig. 1 (the extended unit cell of FeTe is shown in the inset). At room temperature, the reflectance displays the typical metallic form in the Hagen-Rubens regime $R \propto 1 - \sqrt{\omega}$; however, just above T_c the reflectance develops a striking linearfrequency dependence. Below T_c the formation of a superconducting condensate and the opening of a gap in the spectrum of excitations is clearly visible. The reflectance is a complex quantity consisting of an amplitude and a phase, \tilde{r} $=\sqrt{\mathrm{Re}^{i\theta}}$; because only the amplitude $R=\widetilde{rr}^*$ is measured it is



FIG. 1. (Color online) The reflectance of $\text{FeTe}_{0.55}\text{Se}_{0.45}$ in the far-infrared region for light polarized in the Fe-Te planes at several temperatures above and below T_c . Inset: the extended unit cell of FeTe in the tetragonal P4/nmm space group showing the tetrahedrally coordinated Te above and below the Fe planes.



FIG. 2. (Color online) The real part of the in-plane optical conductivity for FeTe_{0.55}Se_{0.45} at several temperatures above and below T_c in the infrared region. Inset: the conductivity in the far-infrared region compared with a model calculation for a single isotropic gap (Δ_0 =4.5 meV, $1/\tau$ =4 Δ_0) superimposed on the Lorentzian contribution.

often not intuitively obvious what changes in the reflectance imply. Consequently, the complex optical properties have been determined from a Kramers-Kronig analysis of the reflectance.³⁵

The temperature dependence of the real part of the optical conductivity is shown in Fig. 2 in the infrared region; the far-infrared region is shown in the inset. At room temperature, the conductivity is relatively flat and structureless, except for a sharp feature associated with the infrared-active E_u mode at 204 cm⁻¹ which is due to the in-plane displacements of the Fe-Te(Se) atoms³⁶ (slightly higher than the E_u mode observed at 187 cm⁻¹ in our examination of Fe_{1.03}Te). As the temperature is lowered there is a redistribution of the spectral weight [defined here as the weight under the conductivity curve over a given interval, $\int_{0+}^{\omega_c} \sigma_1(\omega, T) d\omega$] from high to low frequency. This response is not unusual for a metallic system where the scattering rate decreases with temperature. The optical conductivity is described by a Drude-Lorentz model for the dielectric function $\tilde{\epsilon} = \epsilon_1 + i\epsilon_2$

$$\widetilde{\epsilon}(\omega) = \epsilon_{\infty} - \frac{\omega_{p,D}^2}{\omega^2 + i\omega/\tau_D} + \sum_j \frac{\Omega_j^2}{\omega_j^2 - \omega^2 - i\omega\gamma_j}, \qquad (1)$$

where ϵ_{∞} is the real part of the dielectric function at high frequency, $\omega_{p,D}^2 = 4\pi n e^2/m^*$ and $1/\tau_D$ are the plasma frequency and scattering rate for the delocalized (Drude) carriers, respectively; ω_j , γ_j , and Ω_j are the position, width, and strength of the *j*th vibration or excitation. The complex conductivity is $\tilde{\sigma}(\omega) = \sigma_1 + i\sigma_2 = -i\omega[\tilde{\epsilon}(\omega) - \epsilon_{\infty}]/4\pi$.

The optical conductivity may be reproduced quite well using this approach at 295, 200 and 100 K, with fitted values of $\omega_{p,D}$ =7200 cm⁻¹ and 1/ τ_D =414, 363, and 317 cm⁻¹, respectively (±5%). To fit the midinfrared component, Lorentzian oscillators at the somewhat arbitrary positions of 650 and 3000 cm⁻¹ have been introduced, allowing the free-carrier component to be fit using a single Drude expression,



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FIG. 3. (Color online) The in-plane frequency-dependent scattering rate of FeTe_{0.55}Se_{0.45} for several temperatures above and below T_c in the far-infrared region. The values for $1/\tau_D$ are shown at 295 (\bullet), 200 (\blacksquare), and 100 K (\blacktriangle), respectively, where the scattering rate displays little temperature dependence. For $T \gtrsim T_c$ (18 K) at low frequency $1/\tau(\omega) \propto \omega$ while for $T < T_c$ large changes in the scattering rate are observed in response to the formation of superconducting gap(s).

as opposed to the two-Drude response that has recently been applied to some of the pnictide materials.³² While this approach works well over most of the normal state, it fails for the optical conductivity just above T_c at 18 K, where the low-frequency component is not Drude-like. To address this problem, we consider the extended-Drude model in which the scattering rate takes on a frequency dependence. The experimentally determined scattering rate is³⁷

$$\frac{1}{\tau(\omega)} = \frac{\omega_p^2}{4\pi} \operatorname{Re} \left[\frac{1}{\tilde{\sigma}(\omega)} \right].$$
(2)

In this instance we set $\omega_p = \omega_{p,D}$ and $\epsilon_{\infty} = 4$ [although the choice of ϵ_{∞} has little effect upon $1/\tau(\omega)$ in the far-infrared region]; the temperature dependence of $1/\tau(\omega)$ is shown in Fig. 3 above and below T_c . At 295, 200, and 100 K the scattering rate displays little frequency dependence, and moreover $1/\tau(\omega \rightarrow 0) \simeq 1/\tau_D$. This self-consistent behavior indicates that within this temperature range, the transport may be described as a weakly interacting Fermi liquid (Drude model). However, just above T_c at 18 K the scattering rate develops a linear-frequency dependence $\leq 200 \text{ cm}^{-1}$, suggesting strong electronic correlations.¹⁹ This may be due in part to magnetic correlations²¹ that arise from the suppression of the magnetic transition in $\text{Fe}_{1+\delta}\text{Te}$ at $T_N \simeq 70$ K in response to Se substitution.¹⁴ We note that similar behavior of the scattering rate is observed in optimally doped cuprates where the electronic correlations may have a similar origin.³⁸ Dramatic changes are also observed in $1/\tau(\omega)$ below T_c where the scattering rate is suppressed at low frequencies, but increases rapidly and overshoots the normal-state (18 K) value at about 60 cm⁻¹, finally merging with the normalstate curve at about 200 cm⁻¹; this behavior is in rough agreement with a recently proposed sum rule for the scattering rate.39



FIG. 4. (Color online) The in-plane optical conductivity of $\text{FeTe}_{0.55}\text{Se}_{0.45}$ shown at 6 K (solid line). The calculated optical conductivity with gaps of $2\Delta_1 \approx 5 \text{ meV}$ and $2\Delta_2 \approx 10.2 \text{ meV}$ for $T \ll T_c$ (short-dashed lines) is superimposed on the contribution from the bound excitations in the mid-infrared (long-dashed line); the smoothed linear combination of the three curves (dot-dash line) is in good agreement with the measured data below 200 cm⁻¹.

Returning to the optical conductivity in Fig. 2, below T_c there is a dramatic suppression of the low-frequency conductivity and a commensurate loss of spectral weight which is shown in more detail in the inset. The loss of spectral weight is associated with the formation of a superconducting condensate, whose strength may be calculated from the Ferrell-Glover-Tinkham sum rule: $\int_{0^+}^{\omega_c} [\sigma_1(\omega, T \ge T_c) - \sigma_1(\omega, T \ge T_c)] d\omega_c$ $\ll T_c)]d\omega = \omega_{p,S}^2/8$. Here $\omega_{p,S}^2 = 4\pi n_s e^2/m^*$ is the superconducting plasma frequency and the cut-off frequency ω_c $\simeq 150 \text{ cm}^{-1}$ is chosen so that the integral converges smoothly; the superfluid density is $\rho_{s0} \equiv \omega_{p,s}^2$. The sum rule yields $\omega_{p,S} = 3000 \pm 200 \text{ cm}^{-1}$, indicating that less than onefifth of the free carriers in the normal state have condensed $(\omega_{p,S}^2/\omega_{p,D}^2 \leq 0.18)$. The superfluid density can also be expressed as an effective penetration depth $\lambda_0 = 5300 \pm 300$ Å, which is in good agreement with recent tunnel-diode measurement on FeTe_{0.63}Se_{0.37} (Ref. 40). From the estimate $\sigma_{\rm dc}$ $\equiv \sigma_1(\omega \rightarrow 0) = 3500 \pm 400 \ \Omega^{-1} \text{ cm}^{-1}$ for $T \ge T_c$, this compound is observed to fall on the general scaling line⁴¹ for a BCS superconductor with the condition that $1/\tau \gtrsim 2\Delta$ (the "dirty limit"), $\rho_{s0}/8 \simeq 8.1 \sigma_{dc} T_c$.

The detailed optical conductivity below T_c at 6 K is shown in Fig. 4. In addition to the strong suppression of the conductivity below ~120 cm⁻¹, there is also a prominent shoulder at ~60 cm⁻¹. Below T_c the optical conductivity has been calculated using a Mattis-Bardeen formalism for the contribution from the gapped excitations,^{35,42} as well as the low-frequency tail of the bound midinfrared excitations modeled by Lorentzian oscillators. The Mattis-Bardeen approach assumes that $l \leq \xi_0$, where the mean-free path $l=v_F \tau$ (v_F is the Fermi velocity) and the coherence length is ξ_0 $=\hbar v_F/\pi \Delta_0$ for an isotropic superconducting gap Δ_0 ; this may also be expressed as $1/\tau \geq 2\Delta_0$. This approach is motivated by the observation that less than one-fifth of the free carriers collapse into the condensate, a condition which indicates that these materials are not in the clean limit. Initially, only a

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single isotropic gap $\Delta_0 \simeq 4.5$ meV was considered; however, this failed to accurately reproduce the residual conductivity observed at low frequency (inset in Fig. 2). To properly model the optical conductivity, two gaps at $\Delta_1 \simeq 2.5$ meV and $\Delta_2 \simeq 5.1$ meV are used. For the purposes of this calculation we have assumed a moderate amount of disorder scattering, $1/\tau_i = 4\Delta_i$. The optical conductivity for each of the gaps is shown in Fig. 4 for T=0; the smoothed linear combination of the gaps and the Lorentzian tails is in good agreement with the experimental data. The observation of two gap features is consistent with a number of recent theoretical works that propose that s-wave gaps form on each band, possibly with a sign change between them (s^{\pm}) , in this model the gap on the electron band may be an extended s wave with nodes.^{43,44} The strong reduction of the conductivity at low frequency for $T \ll T_c$ suggests the absence of nodes. It is possible that disorder may lift the nodes, resulting in a nodeless extended s-wave gap.45,46 The optical results provide estimates of the gap amplitudes but do not distinguish between s^{\pm} and extended s wave. The optical gaps $2\Delta_i \simeq 40$ and 82 cm⁻¹ are similar to or larger than the low-frequency scattering rate observed at 18 K, $1/\tau(\omega \rightarrow 0) \simeq 40 \text{ cm}^{-1}$. While this might seem to cast doubt on the validity of the Mattis-Bardeen approach, we note that the strong frequency dependence of the scattering rate at this temperature complicates matters. If we consider the value of the $1/\tau(\omega)$ in the region of the optical gaps $2\Delta_j$ where the scattering should be important, we find from Fig. 3 that the scattering rate is then larger than the gap amplitude

$$\frac{1/\tau_j(2\Delta_j)}{2\Delta_i}\approx 3,$$

which is actually larger than the ratio used in the calculation, indicating that the Mattis-Bardeen approach is correct. Finally, we note that while $2\Delta_1/k_BT_c \approx 4$ is close to the value of 3.5 expected in the BCS weak-coupling limit,⁴ $2\Delta_2/k_BT_c \approx 8.4$ is significantly larger.

To summarize, the optical properties of FeTe_{0.55}Se_{0.45} $(T_c=14 \text{ K})$ have been examined for light polarized in the Fe-Te(Se) planes above and below T_c . Well above T_c the transport may be described by a weakly interacting Fermi liquid (Drude model); however, this picture breaks down close to T_c when the scattering rate takes on a strong frequency dependence, similar to what is observed in the cuprate superconductors. Below T_c , less than one-fifth of the free carriers collapse into the condensate ($\lambda_0 \simeq 5300$ Å), indicating that this material is in the dirty limit, and indeed this material falls on the general scaling line predicted for a BCS dirty-limit superconductor. To successfully model the optical conductivity, two gaps of $\Delta_1 \simeq 2.5 \text{ meV}$ and $\Delta_2 \simeq 5.1 \text{ meV}$ are considered using a Mattis-Bardeen formalism (with moderate disorder scattering), suggesting either an s^{\pm} or a nodeless extended *s*-wave gap.

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